BFG 19S E6327

BFG 19S E6327 Information

For Reference Only

Part Number BFG 19S E6327
Manufacturer Infineon Technologies
Category Discrete Semiconductor Products
Transistors - Bipolar (BJT) - RF
Description TRANSISTOR RF NPN 15V SOT-223
Package TO-261-4, TO-261AA

For the pricing/inventory/lead time, please contact us
Website: https://www.heisener.com
E-mail: salesdept@heisener.com

Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.

BFG 19S E6327 Specifications

Manufacturer Part Number	BFG 19S E6327
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - RF
Package	TO-261-4, TO-261AA
Series	-
Transistor Type	NPN
Voltage - Collector Emitter Breakdown (Max)	15V
Frequency - Transition	5.5GHz
Noise Figure (dB Typ @ f)	2dB ~ 3dB @ 900MHz ~ 1.8GHz
Gain	14dB ~ 8.5dB
Power - Max	1W
DC Current Gain (hFE) (Min) @ Ic, Vce	70 @ 70mA, 8V
Current - Collector (Ic) (Max)	210mA
Operating Temperature	150°C (TJ)
Mounting Type	Surface Mount
Package / Case	TO-261-4, TO-261AA
Supplier Device Package	PG-SOT223-4
	Report errors?

BFG 19S E6327 Guarantees

Quality Guarantees
We provide 90 days warranty. *
If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

Service Guarantees
We guarantee 100% customer satisfaction.
Our experienced sales team and tech support team back our services to satisfy all our customers.

BFG 19S E6327 Payment Methods

BFG 19S E6327 Shipping Methods

If you have any question about BFG 19S E6327, please do not hesitate to contact us!
Website: https://www.heisener.com
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